

Supplementary Information

Biomimetic Silicon Nitride Skeleton with Oriented Microstructures in Epoxy

Resin for High Thermal Conductivity and Low Thermal Expansion

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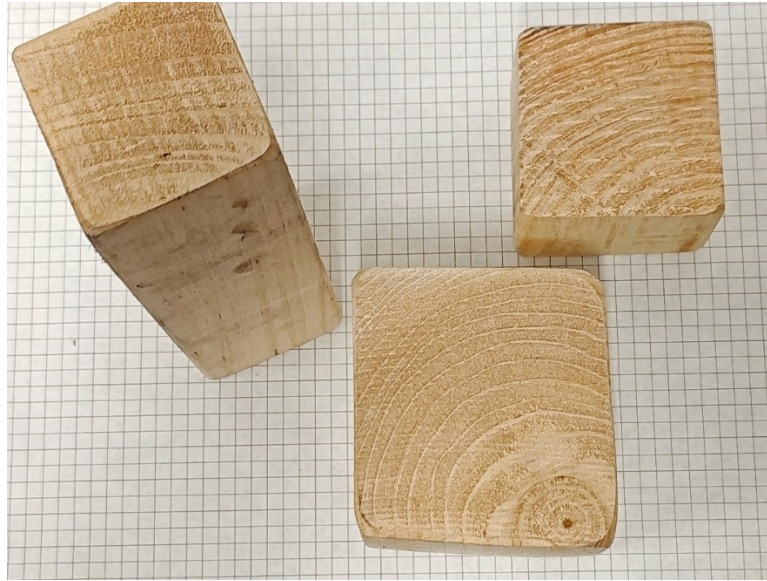


Fig. S1 Digital photos of spruce

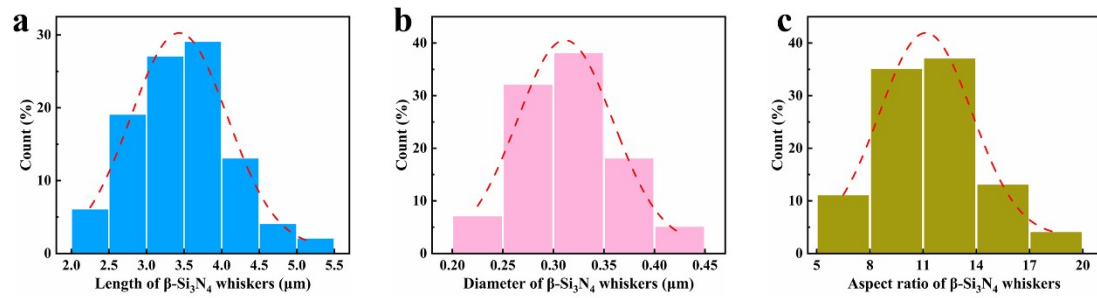


Fig. S2 (a) Length; (b) diameter and (c) aspect ratio of β -Si₃N₄ whisker measured from SEM images.

Table S1. Comparison of thermal conductivity data with other representative polymer composites form the literature.

Sample	Filler content (Vol.%)	TC ($\text{W}\cdot\text{m}^{-1}\cdot\text{K}^{-1}$)	Ref
BN-SiC/EP	40	5.77	[1]
40-SiC/EP	40	3.15	[2]
SiC/EP	40	1.87	
28-SiC/EP	28	1.23	[3]
36-Al ₂ O ₃ /EP	36	3.17	[4]
43-Al ₂ O ₃ /EP	43	4.36	[5]
Al ₂ O ₃ /EP	25	6.71	[6]
25-Al ₂ O ₃ /EP	25	3.01	
AlN-Fe ₃ O ₄ /EP	41	3.14	[7]
45-Si ₃ N ₄ /EP	45	1.75	[8]
35-Si ₃ N ₄ /EP	35	1.55	
40-Si ₃ N ₄ /EP	40	1.4	[9]
23-Si ₃ N ₄ /EP	23	3.8	
16-Si ₃ N ₄ /EP	16	1.8	
22-Si ₃ N ₄ /EP	22	3.89	[10]
15-BNNs/EP	15	5.19	
9-BNNs/EP	9	2.85	[11]
13-BNNs/EP	13	5.05	[12]
10-BNNs/EP	10	3.13	[13]
4-BNNs/EP	4	1.56	
G/MLG/EP	10	5.1	[14]
GNP/EP	25	6.44	[15]
Al particle/EP	48	1.47	[16]
AgNW/EP	4	0.9	[17]
Bio-Si ₃ N ₄ /EP	38	8.26	This work

Table S2. Material properties used in the finite element simulations.

Properties	Si₃N₄	EP
Thermal conductivity (W·m ⁻¹ ·K ⁻¹)		0.18
Density (g·cm ⁻³)		1.8
Heat capacity (J·kg ⁻¹ ·K ⁻¹)	COMSOL Multiphysics Material Library	1.4
Young's modulus (GPa)	(β-Si ₃ N ₄ , c-axis)	2.5
Poisson's ratio		0.38
Coefficient of thermal expansion (K ⁻¹)		74.3 × 10 ⁻⁶

Table S3. The average displacement of each surface of the models.

Model	Direction	Surface	Displacement (μm)	Size (μm)	Linear expansivity (%)
A single unit	x	left	-0.0016098	22.0	0.01465
		right	0.0016138		
	y	front	-0.00090103	17.0	0.01062
		back	0.00090383		
	z	bottom	-0.0010804	19.5	0.01106
		top	0.0010758		
Multiple units	x	left	-0.015915	200	0.01434
		right	0.015919		
	y	front	-0.0095787	200	0.00861
		back	0.0095788		
	z	bottom	-0.018078	200	0.01629
		top	0.01808		

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